Product Datasheet Product ID: BMBP29R35/5R1-6PA



EC MICROWAVE

The door to the RF world

Thin Film ceramic Filte BMBP29R35/5R1-6PA

Precautions

1. The chip is recommended sub-cavity use, both sides of the side wall from about 0.2mm, surface distance Cover about 3mm, the chip ports are interchangeable;

2. Chip recommended low-stress conductive adhesive (such as ME8456) bonding;

3. Chip should be installed in Kovar (recommended) or molybdenum copper with ceramic thermal expansion coefficient(6.7ppm / °C) on the carrier, the carrier thickness ≥ 0.2mm;

4 circuit board micro-chip wire bonding connection, it is recommended microstrip bonding at mining T-type structure to match, T-size as right

Features

high-precision film processing technology		
high performance, low temperature drift, high power		
Ceramic substrate, 50Ω coplanar waveguide output		
Gold wire bonding, suitable for multi-chip integrated module applications		

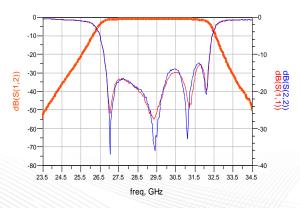
Environmental parameters

Working temperature	-55°C~+85°C
storage temperature	-55°C~+125°C
Maximum input power	35dBm

Electrical Specifications

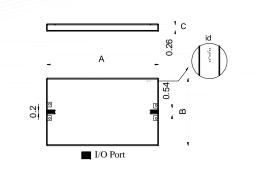
Center frequency(f0)	29.35
Passband frequency range (GHz)	26.8-31.2
Band fluctuations (dB)	1
Center insertion loss (dB)	1.5
Return loss (dB)	13
Band attenuation (dB)	≥ 40@24.1GHz ≥ 40@34.0GHz

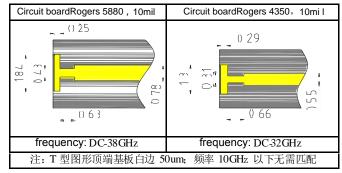
Band rejection & Return loss $\,\rm VS$ frequency $(T_A\!=\!\!25^\circ\!\rm C\,)$



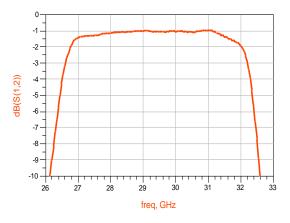
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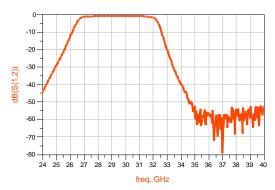




Passband loss VS frequency (T A=25°C)



Distal inhibition $_{VS}$ frequency (T_A=25 $^\circ\!\mathrm{C}$)



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